

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)}$ max	I_D $T_A = 25^\circ C$
-30V	70mΩ @ $V_{GS} = -10V$	-3.8A
	120mΩ @ $V_{GS} = -4.5V$	-3.0A

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

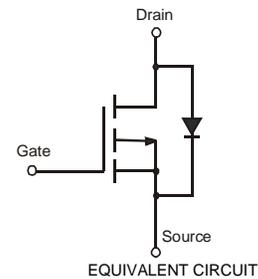
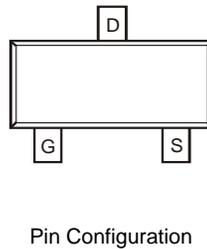
Description and Applications

This new generation MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Power management functions
- Analog Switch
- Load Switch
- Boost Switch

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)

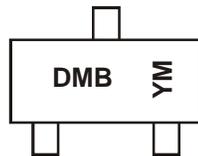


Ordering Information (Note 3)

Part Number	Case	Packaging
DMP3098L-7	SOT23	3000/Tape & Reel

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at <http://www.diodes.com>.
 3. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information



DMB = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: V = 2008)
 M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	2010	2011	2012	2013	2014	2015
Code	V	W	X	Y	Z	A	B	C

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	± 20	V
Drain Current (Note 4) $V_{GS} = -10\text{V}$	Steady State	$T_A = 25^\circ\text{C}$	I_D	-3.8	A
		$T_A = 70^\circ\text{C}$		-2.9	
Pulsed Drain Current (Note 5)			I_{DM}	-11	A

Thermal Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 4)	P_D	1.08	W
Thermal Resistance, Junction to Ambient @ $T_A = 25^\circ\text{C}$ (Note 4)	$R_{\theta JA}$	115	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV_{DSS}	-30	—	—	V	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-800	nA	$V_{DS} = -30\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	-1.8	-2.1	V	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(on)}$	—	56	70	m Ω	$V_{GS} = -10\text{V}, I_D = -3.8\text{A}$
			98	120		$V_{GS} = -4.5\text{V}, I_D = -3.0\text{A}$
Forward Transfer Admittance	$ Y_{fs} $	—	3.6	—	S	$V_{DS} = -5\text{V}, I_D = -2.7\text{A}$
Diode Forward Voltage (Note 6)	V_{SD}	—	—	-1.26	V	$V_{GS} = 0\text{V}, I_S = -2.7\text{A}$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C_{iss}	—	336	1008	pF	$V_{DS} = -25\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	—	70	210	pF	
Reverse Transfer Capacitance	C_{rss}	—	49	147	pF	
Gate Resistance	R_G	—	4.6	—	Ω	$V_{GS} = 0\text{V}, V_{DS} = 0\text{V}, f = 1\text{MHz}$
SWITCHING CHARACTERISTICS (Note 7)						
Total Gate Charge	Q_g	—	4.0	8.0	nC	$V_{DS} = -15\text{V}, V_{GS} = -4.5\text{V}, I_D = -3.8\text{A}$
			7.8	—		$V_{DS} = -15\text{V}, V_{GS} = -10\text{V}, I_D = -3.8\text{A}$
Gate-Source Charge	Q_{gs}	—	1.0	—	ns	$V_{DS} = -15\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_G = 6.0\Omega$
Gate-Drain Charge	Q_{gd}	—	2.5	—		
Turn-On Delay Time	$t_{d(on)}$	—	6.0	12.0	ns	$V_{DS} = -15\text{V}, V_{GS} = -10\text{V}, I_D = -1\text{A}, R_G = 6.0\Omega$
Rise Time	t_r	—	5.0	10.0		
Turn-Off Delay Time	$t_{d(off)}$	—	17.6	35.2		
Fall Time	t_f	—	9.5	19.0		

- Notes:
4. Device mounted on FR-4 PCB on 2 oz., 0.5 in.² copper pads and $t \leq 5$ sec.
 5. Pulse width $\leq 10\mu\text{s}$, Duty Cycle $\leq 1\%$.
 6. Short duration pulse test used to minimize self-heating effect.
 7. Guaranteed by design. Not subject to production testing.

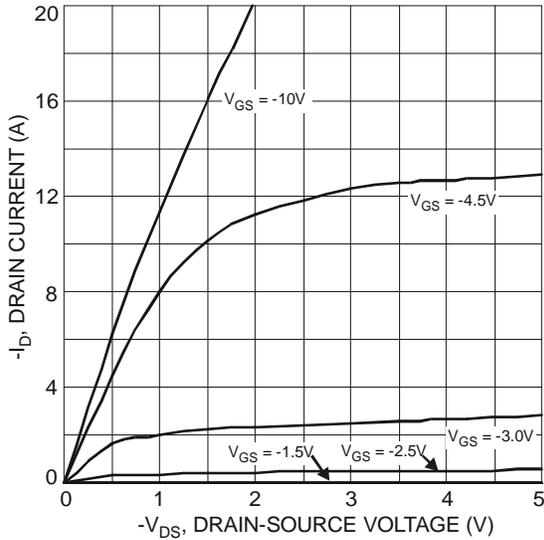


Fig. 1 Typical Output Characteristics

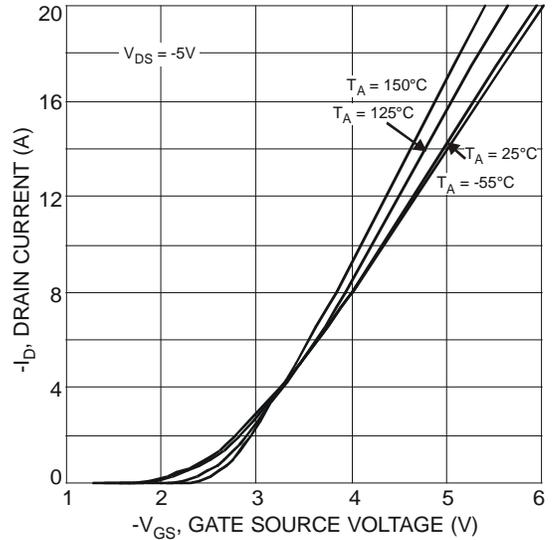


Fig. 2 Typical Transfer Characteristics

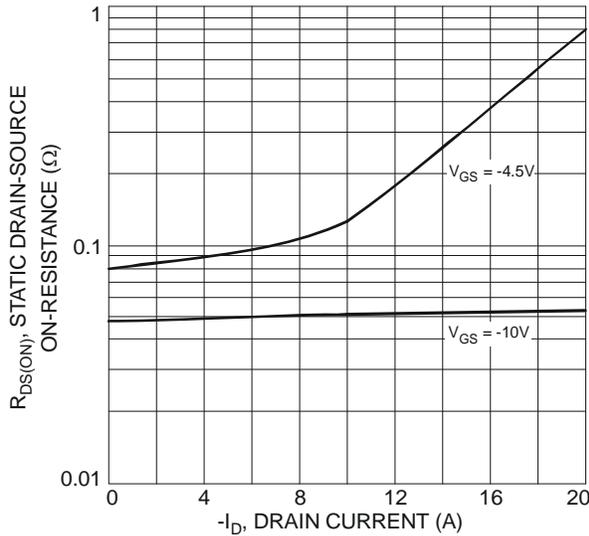


Fig. 3 Typical On-Resistance vs. Drain Current and Gate Voltage

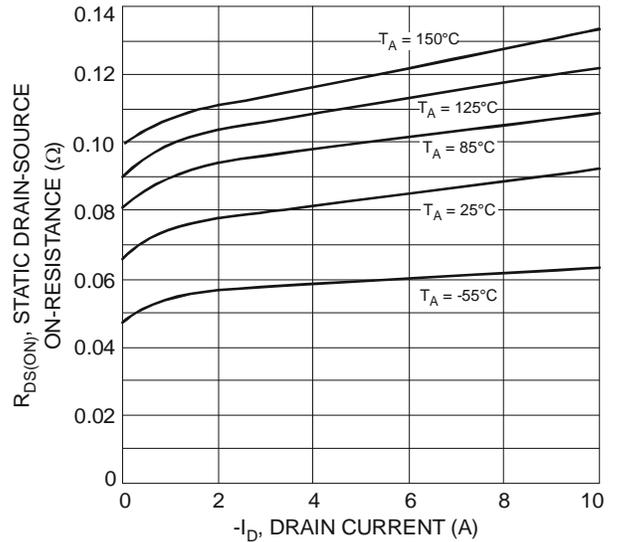


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

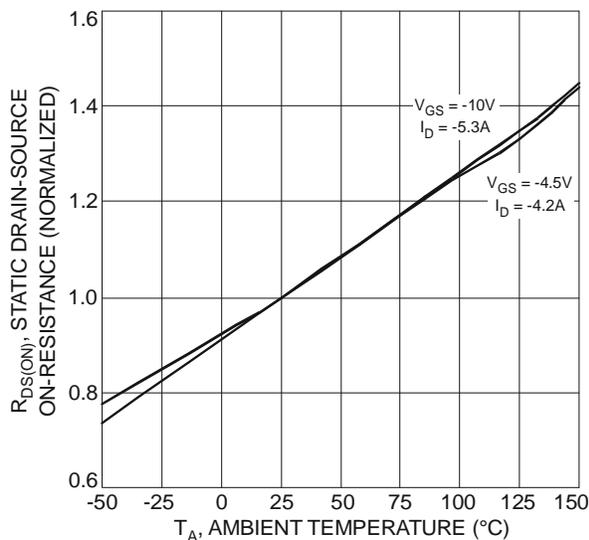


Fig. 5 On-Resistance Variation with Temperature

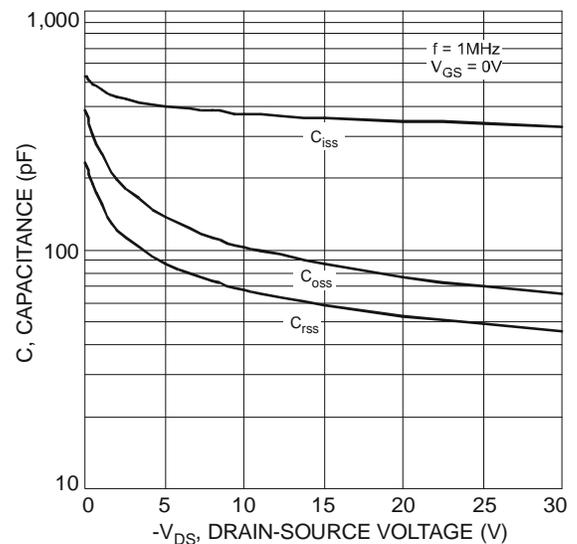


Fig. 6 Typical Capacitance

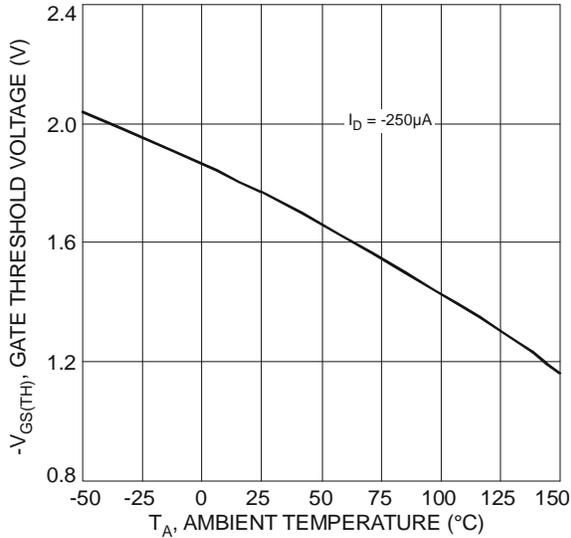


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

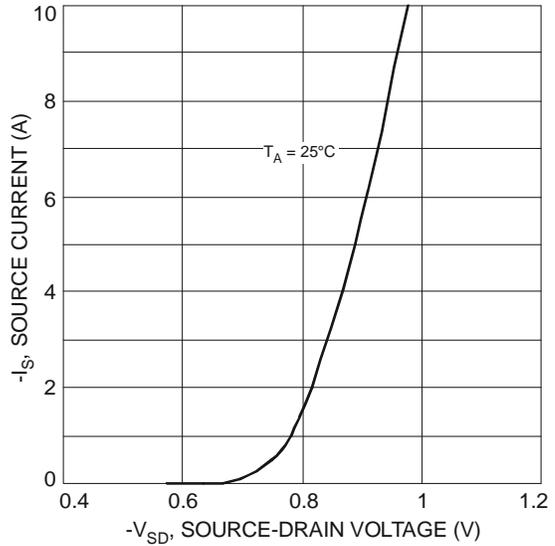


Fig. 8 Diode Forward Voltage vs. Current

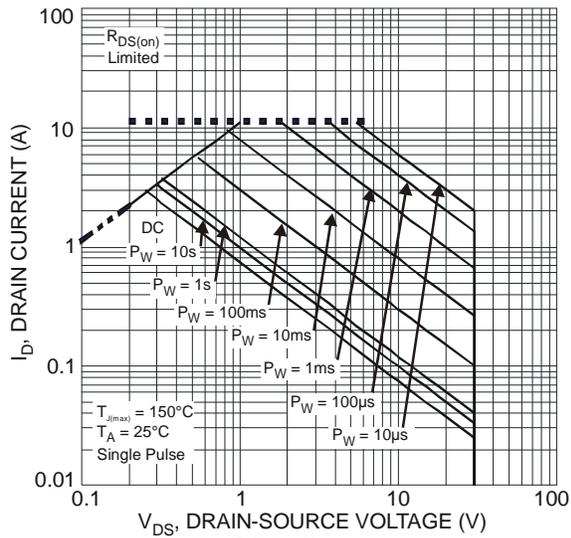
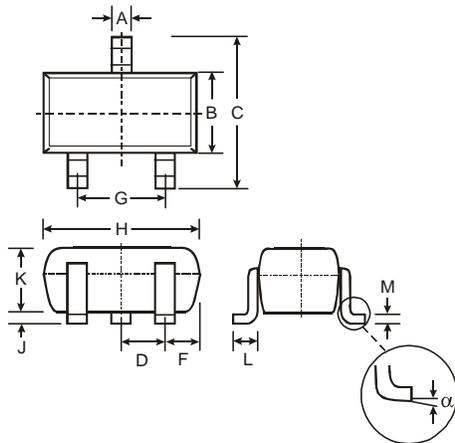


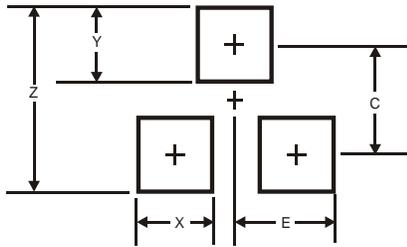
Fig. 9 Safe Operation Area

Package Outline Dimensions



SOT23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
F	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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- Подбор аналогов;
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- Техническая поддержка проекта;
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